



Micron Technology



MT53B128M32D1DS-062 AAT:A

Part Number:	MT53B128M32D1DS-062 AAT:A
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 4G 1600MHZ
Datasheets:	
RoHs Status	 Lead free / RoHS Compliant
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.

Specifications of MT53B128M32D1DS-062 AAT:A

PART NUMBER	MT53B128M32D1DS-062 AAT:A
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 4G 1600MHZ
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DATA SHEET	
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	1.1V
TECHNOLOGY	SDRAM - Mobile LPDDR4
SERIES	-
OTHER NAMES	MT53B128M32D1DS-062 AAT:A-ND MT53B128M32D1DS-062AAT:A
OPERATING TEMPERATURE	-40°C ~ 105°C (TA)
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	4Gb (128M x 32)
MEMORY INTERFACE	-
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - Mobile LPDDR4 Memory IC 4Gb (128M x 32) 1600MHZ
CLOCK FREQUENCY	1600MHz

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